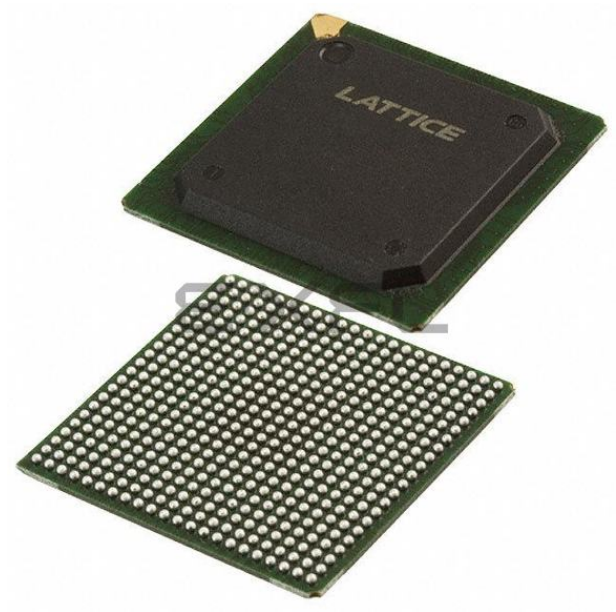
Lattice Semiconductor Corporation - LC5512MV-75F484C Datasheet



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Understanding Embedded - CPLDs (Complex Programmable Logic Devices)

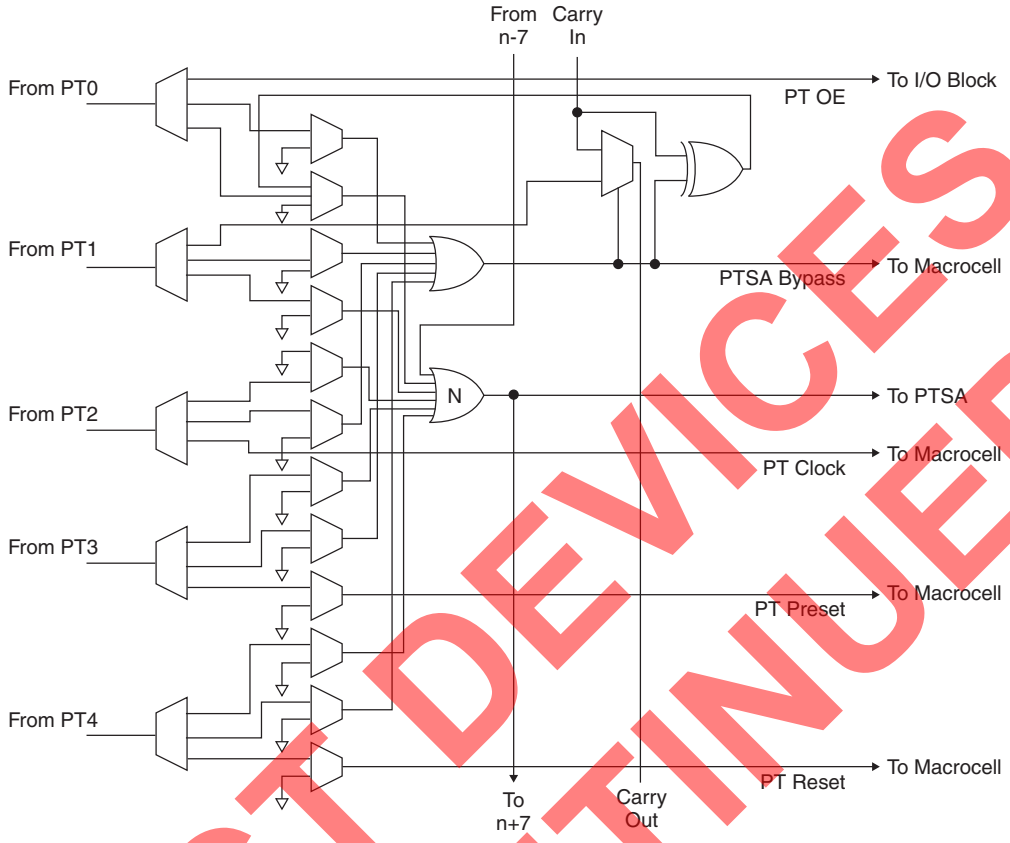
Embedded - CPLDs, or Complex Programmable Logic Devices, are highly versatile digital logic devices used in electronic systems. These programmable components are designed to perform complex logical operations and can be customized for specific applications. Unlike fixed-function ICs, CPLDs offer the flexibility to reprogram their configuration, making them an ideal choice for various embedded systems. They consist of a set of logic gates and programmable interconnects, allowing designers to implement complex logic circuits without needing custom hardware.

Applications of Embedded - CPLDs

Details	
Product Status	Obsolete
Programmable Type	In System Programmable
Delay Time tpd(1) Max	7.5 ns
Voltage Supply - Internal	3V ~ 3.6V
Number of Logic Elements/Blocks	16
Number of Macrocells	512
Number of Gates	-
Number of I/O	253
Operating Temperature	0°C ~ 90°C (TJ)
Mounting Type	Surface Mount
Package / Case	484-BBGA
Supplier Device Package	484-FPBGA (23x23)
Purchase URL	https://www.e-xfl.com/product-detail/lattice-semiconductor/lc5512mv-75f484c

Product Line	Ordering Part Number	Product Status	Reference PCN
LC5512MC (Cont'd)	LC5512MC-45F484C	**Discontinued**	PCN#09-10
	LC5512MC-45FN484C		
	LC5512MC-75F484C		
	LC5512MC-75FN484C		
	LC5512MC-75F484I		
	LC5512MC-75FN484I		
LC5768MV	LC5768MV-5F256C	Active / Orderable	
	LC5768MV-5FN256C		
	LC5768MV-75F256C		
	LC5768MV-75FN256C		
	LC5768MV-75F256I		
	LC5768MV-75FN256I		
	LC5768MV-5F484C		
	LC5768MV-5FN484C		
	LC5768MV-75F484C		
	LC5768MV-75FN484C		
	LC5768MV-75F484I		
	LC5768MV-75FN484I		
LC5768MB	LC5768MB-5F256C	**Discontinued**	PCN#09-10
	LC5768MB-5FN256C		
	LC5768MB-75F256C		
	LC5768MB-75FN256C		
	LC5768MB-75F256I		
	LC5768MB-75FN256I		
	LC5768MB-5F484C		
	LC5768MB-5FN484C		
	LC5768MB-75F484C		
	LC5768MB-75FN484C		
	LC5768MB-75F484I		
	LC5768MB-75FN484I		
LC5768MC	LC5768MC-5F256C	**Discontinued**	PCN#09-10
	LC5768MC-5FN256C		
	LC5768MC-75F256C		
	LC5768MC-75FN256C		
	LC5768MC-75F256I		
	LC5768MC-75FN256I		
	LC5768MC-5F484C		
	LC5768MC-5FN484C		
	LC5768MC-75F484C		
	LC5768MC-75FN484C		
	LC5768MC-75F484I		
	LC5768MC-75FN484I		

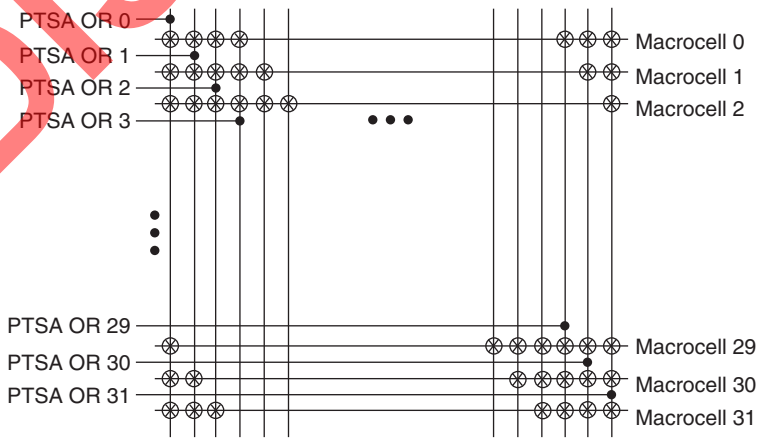
Figure 6. Dual-OR PT Sharing Array



Product Term Sharing Array

The Product Term Sharing Array (PTSA) consists of 32 inputs from the Dual-OR Array (Expandable PTSA OR) and 32 outputs directly to the macrocells. Each output is the OR term of any combination of the seven Expandable PTSA OR terms connected to that output. Every Nth macrocell is connected to N-3, N-2, N-1, N, N+1, N+2 and N+3 PTSA OR terms via a programmable connection. This wraps around the logic, for example, Macrocell 0 gets its logic from 29, 30, 31, 0, 1, 2, 3. The Expandable PTSA OR used in conjunction with the PTSA allows wide functions to be implemented easily and efficiently. Without using the Expandable PTSA OR capability, the greatest number of product terms that can be included in a single function with one pass of delay is 35. Up to 160 product terms can be included in a single function through the use of the expandable PTSA OR capability. Figure 7 shows the graphical representation of the PTSA.

Figure 7. Product Term Sharing Array (PTSA)



Pseudo Dual-Port SRAM Mode

In Pseudo Dual-Port SRAM Mode the multi-function array is configured as a SRAM with an independent read and write ports that access the same 16,384-bits of memory. Data widths of 1, 2, 4, 8, 16 and 32 are supported by the MFB. Figure 10 shows the block diagram of the Pseudo Dual-Port SRAM.

Write data, write address, chip select and write enable signals are always synchronous (registered). The read data and read address signals can be synchronous or asynchronous. Reset is asynchronous. All write signals share the same clock, and clock enable. All read signals share the same clock and clock enable. Reset is shared by both read and write signals. Table 6 shows the possible sources for the clock, clock enable and initialization signals for the various registers.

Figure 10. Pseudo Dual-Port SRAM Block Diagram

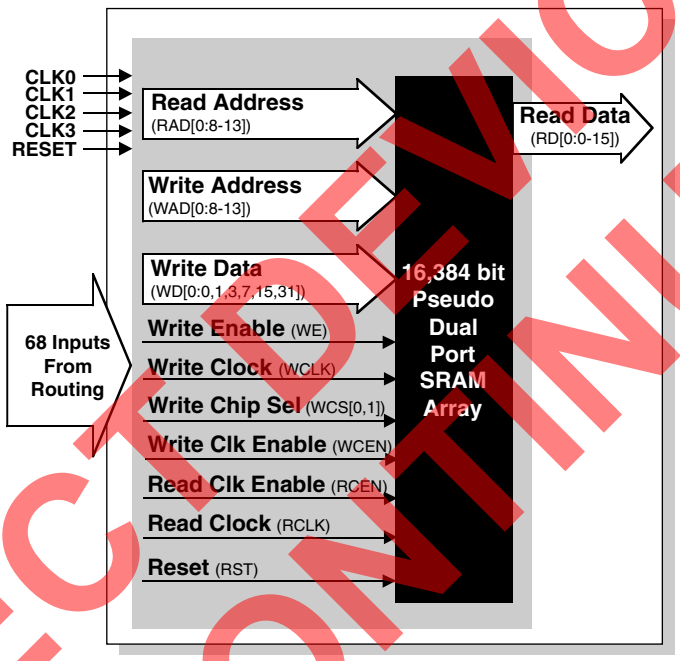


Table 6. Register Clock, Clock Enable, and Reset in Pseudo Dual-Port SRAM Mode

Register	Input	Source
Write Address, Write Data, Write Enable, and Write Chip Select	Clock	WCLK or one of the global clocks (CLK0 - CLK3). The selected signal can be inverted if desired.
	Clock Enable	WCEN or one of the global clocks (CLK1 - CLK2). The selected signal can be inverted if desired.
	Reset	Created by the logical OR of the global reset signal and RST. RST may have inversion if desired.
Read Data and Read Address	Clock	RCLK or one of the global clocks (CLK0 - CLK3). The selected signal can be inverted if desired.
	Clock Enable	RCEN or one of the global clocks (CLK1 - CLK2). The selected signal can be inverted if desired.
	Reset	Created by the logical OR of the global reset signal and RST. RST may have inversion if desired.

Output Sharing Array (OSA)

A number of I/O pads are available in each sysIO bank to route the selected number of macrocells from the MFB outputs directly to the I/O pads in logic mode. In the ispXPLD 5000MX, the large number of inputs and PTs to the MFB as well as the presence of the PTSA can cover most routing flexibility of signals to I/O cells. The Output Sharing Array gives additional routing capability and I/O access to an MFB when a wide output function takes up the whole MFB and cannot be easily divided across multiple MFBs. By using the OSA, the wide output function, such as 32-bit FIFO, can have all of its output signals from the one MFB routed to I/O cells. In a given I/O block, the wide output functions must share the I/O pads with other logic functions.

The OSA bypass option routes the MFB signal directly to the I/O cell, allowing a direct connection to the I/O cell. The logic functions use the option to provide faster speed to the outputs. The Logic Signal Connection tables list the OSA bypass as the primary macrocell and OSA options as alternate macrocells. Similarly, the Alternate Input listing in the table shows the alternate macrocell input connection for a given I/O pin. Figure 17 shows the alternate macrocell connections in an I/O cell.

sysIO Banks

The ispXPLD 5000MX devices are divided into four sysIO banks, consisting of multiple I/O cells, where each bank is capable of supporting 16 different I/O standards. Each sysIO bank has its own I/O voltage (V_{CCO}) and reference voltage (V_{REF}) resources allowing complete independence from the others.

I/O Cell

The I/O cell of the ispXPLD 5000MX devices contains an output enable (OE) MUX, a programmable tri-state output buffer, a programmable input buffer, and programmable bus-maintenance circuitry.

The I/O cell receives inputs from its associated macrocells and the device pin. The I/O cell has a feedback line to its associated macrocells and a direct path to GRP. The output enable (OE) MUX selects the OE signal per I/O cell. The inputs to the OE MUX are the four global PTOE signals, PTOE and the two GOE signals. The OE MUX also has the ability to choose either the true or inverse of each of these signals. The output of the OE MUX goes through a logical AND with the TOE signal to allow easy tri-stating of the outputs for testing purposes. The MFBs are grouped into segments of four for the purpose of generating Shared PTOE signals. Each Shared PTOE signal is derived from PT 163 from one of the four MFBs. Table 10 shows the segments. The PTOE signal is derived from the first product term in each macrocell cluster, which is directly routed to the OE MUX. Therefore, every I/O cell can have a different OE signal. Figure 17 is a graphical representation of the I/O cell.

Figure 17. I/O Cell

Table 10. Shared PTOE Segments

Device	MFBs Associated With Segments
ispXPLD 5256MX	(A, B, C, D) (E, F, G, H)
ispXPLD 5512MX	(A, B, C, D) (E, F, G, H) (I, J, K, L) (M, N, O, P)
ispXPLD 5768MX	(A, B, C, D) (E, F, G, H) (I, J, K, L) (M, N, O, P) (Q, R, S, T) (U, V, W, Z)
ispXPLD 51024MX	(A, B, C, D) (E, F, G, H) (I, J, K, L) (M, N, O, P) (Q, R, S, T) (U, V, W, Z) (Y, Z, AA, AB) (AC, AD, AE, AF)

sysIO Standards

Each I/O within a bank is individually configurable based on the V_{CCO} and V_{REF} settings. Some standards also require the use of an external termination voltage. Table 12 lists the sysIO standards with the typical values for V_{CCO}, V_{REF} and V_{TT}. For more information on the sysIO capability, refer to TN1000, sysIO Usage Guidelines for Lattice Devices.

Table 11. Number of I/Os per Bank

Device	Maximum Number of I/Os per Bank (n)
ispXPLD 5256MX	36
ispXPLD 5512MX	68
ispXPLD 5768MX	96
ispXPLD 51024MX	96

Supply Current

Symbol	Parameter	Condition	Min.	Typ.[3]	Max.	Units
ispXPLD 5256						
I_{CC}[1,2]	Operating Power Supply Current	V_{CC} = 3.3V, f = 1.0MHz	—	26	—	mA
		V_{CC} = 2.5V, f = 1.0MHz	—	26	—	mA
		V_{CC} = 1.8V, f = 1.0MHz	—	16	—	mA
I_{CCO}	Standby Power Supply Current (per I/O Bank)	V_{CCO} = 3.3V, f = 1.0MHz, unloaded	—	4	—	mA
		V_{CCO} = 2.5V, f = 1.0MHz, unloaded	—	4	—	mA
		V_{CCO} = 1.8V, f = 1.0MHz, unloaded	—	3	—	mA
I_{CCP}	PLL Power Supply Current (per PLL Bank)	V_{CCP} = 3.3V, f = 10MHz	—	11	—	mA
		V_{CCP} = 2.5V, f = 10MHz	—	11	—	mA
		V_{CCP} = 1.8V, f = 10MHz	—	3	—	mA
I_{CCJ}	Standby IEEE 1149.1 TAP Power Supply Current	V_{CCJ} = 3.3V	—	1	—	mA
		V_{CCJ} = 2.5V	—	1	—	mA
		V_{CCJ} = 1.8V	—	1	—	mA
ispXPLD 5512						
I_{CC}[1,2]	Operating Power Supply Current	V_{CC} = 3.3V, f = 1.0MHz	—	33	—	mA
		V_{CC} = 2.5V, f = 1.0MHz	—	33	—	mA
		V_{CC} = 1.8V, f = 1.0MHz	—	22	—	mA
I_{CCO}	Standby Power Supply Current (per I/O Bank)	V_{CCO} = 3.3V, f = 1.0MHz, unloaded	—	4	—	mA
		V_{CCO} = 2.5V, f = 1.0MHz, unloaded	—	4	—	mA
		V_{CCO} = 1.8V, f = 1.0MHz, unloaded	—	3	—	mA
I_{CCP}	PLL Power Supply Current (per PLL Bank)	V_{CCP} = 3.3V, f = 10MHz	—	11	—	mA
		V_{CCP} = 2.5V, f = 10MHz	—	11	—	mA
		V_{CCP} = 1.8V, f = 10MHz	—	3	—	mA
I_{CCJ}	Standby IEEE 1149.1 TAP Power Supply Current	V_{CCJ} = 3.3V	—	1	—	mA
		V_{CCJ} = 2.5V	—	1	—	mA
		V_{CCJ} = 1.8V	—	1	—	mA
ispXPLD 5768						
I_{CC}[1,2]	Operating Power Supply Current	V_{CC} = 3.3V, f = 1.0MHz	—	40	—	mA
		V_{CC} = 2.5V, f = 1.0MHz	—	40	—	mA
		V_{CC} = 1.8V, f = 1.0MHz	—	30	—	mA
I_{CCO}	Standby Power Supply Current (per I/O Bank)	V_{CCO} = 3.3V, f = 1.0MHz, unloaded	—	4	—	mA
		V_{CCO} = 2.5V, f = 1.0MHz, unloaded	—	4	—	mA
		V_{CCO} = 1.8V, f = 1.0MHz, unloaded	—	3	—	mA
I_{CCP}	PLL Power Supply Current (per PLL Bank)	V_{CCP} = 3.3V, f = 10MHz	—	11	—	mA
		V_{CCP} = 2.5V, f = 10MHz	—	11	—	mA
		V_{CCP} = 1.8V, f = 10MHz	—	3	—	mA
I_{CCJ}	Standby IEEE 1149.1 TAP Power Supply Current	V_{CCJ} = 3.3V	—	1	—	mA
		V_{CCJ} = 2.5V	—	1	—	mA
		V_{CCJ} = 1.8V	—	1	—	mA

sysIO Differential DC Electrical Characteristics

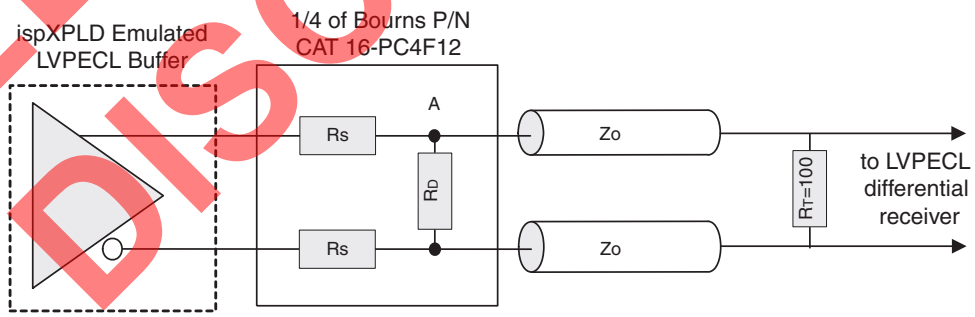
Over Recommended Operating Conditions

Parameter	Description	Test Conditions	Min.	Typ.	Max.
LVDS					
V_{INP}	Input Voltage		0V	—	2.4V
V_{THD}	Differential Input Threshold	0.2 ð V_{CM} ð 1.8V	+/-100mV	—	—
I_{IN}	Input Current	Power On	—	—	+/-10uA
V_{OH}	Output High Voltage for V_{OP} or V_{OM}	RT = 100 Ohm	—	1.38V	1.60V
V_{OL}	Output Low Voltage for V_{OP} or V_{OM}	RT = 100 Ohm	0.9V	1.03V	—
V_{OD}	Output Voltage Differential	(V_{OP} - V_{OM}), R_T = 100 Ohm	250mV	350mV	450mV
ΔV_{OD}	Change in V_{OD} Between High and Low		—	—	50mV
V_{OS}	Output Voltage Offset	(V_{OP} - V_{OM})/2, R_T = 100 Ohm	1.125V	1.20V	1.375V
ΔV_{OS}	Change in V_{OS} Between H and L		—	—	50mV
I_{OSD}	Output Short Circuit Current	V_{OD} = 0V Driver outputs shorted	—	—	24mA

LVPECL[1]								
DC Parameter	**Parameter Description**	**Min.**	**Max.**	**Min.**	**Max.**	**Min.**	**Max.**	**Units**
V_{CCO}		**3.0**		**3.3**		**3.6**		**V**
V_{IH}	Input Voltage High	1.49	2.72	1.49	2.72	1.49	2.72	V
V_{IL}	Input Voltage Low	0.86	2.125	0.86	2.125	0.86	2.125	V
V_{OH}	Output Voltage High	1.7	2.11	1.92	2.28	2.03	2.41	V
V_{OL}	Output Voltage Low	0.96	1.27	1.06	1.43	1.3	1.57	V
V_{DIFF}[2]	Differential Input voltage	0.3	—	0.3	—	0.3	—	V

1. These values are valid at the output of the source termination pack as shown above with 100-ohm differential load only (see Figure 19). The V_{OH} levels are 200mV below the standard LVPECL levels and are compatible with devices tolerant of the lower common mode ranges.
2. Valid for 0.2 ð V_{CM} ð 1.8V

Figure 19. LVPECL Driver with Three Resistor Pack



ispXPLD 5000MX Family External Switching Characteristics [1, 2, 3]

Over Recommended Operating Conditions

Parameter	Description	-4		-45		-5		-52		-75		Units
		Min.	Max.	Min.	Max.	Min.	Max.	Min.	Max.	Min.	Max.	
t_{PD}	Data Propagation Delay, 5-PT Bypass	—	4.0	—	4.5	—	5.0	—	5.2	—	7.5	ns
t_{PD_PTSA}	Data propagation delay	—	4.8	—	5.7	—	6.0	—	6.5	—	9.5	ns
t_S	MFB Register Setup Time Before Clock, 5-PT Bypass	2.2	—	2.8	—	2.8	—	3.0	—	4.5	—	ns
t_{S_PTSA}	MFB Register Setup Time Before Clock	2.5	—	3.1	—	3.1	—	3.6	—	5.5	—	ns
t_{SIR}	MFB Register Setup Time Before Clock, Input Register Path	1.0	—	1.0	—	1.0	—	0.5	—	1.7	—	ns
t_H	MFB Register Hold Time Before Clock, 5-PT Bypass	0.0	—	0.0	—	0.0	—	0.0	—	0.0	—	ns
t_{H_PTSA}	MFB Register Hold Time Before Clock	0.0	—	0.0	—	0.0	—	0.0	—	0.0	—	ns
t_{HIR}	MFB Register Hold Time Before Clock, Input Register Path	0.5	—	0.5	—	0.5	—	1.0	—	1.3	—	ns
t_{CO}	MFB Register Clock-to-Output Delay	—	2.8	—	3.0	—	3.2	—	3.7	—	5.0	ns
t_R	External Reset Pin to Output Delay	—	4.0	—	4.5	—	5.0	—	5.0	—	7.5	ns
t_{RW}	Reset Pulse Duration	1.8	—	1.8	—	1.8	—	2.0	—	3.0	—	ns
$t_{LPTOE/DIS}$	Input to Output Local Product Term Output Enable/Disable	—	6.0	—	7.0	—	7.5	—	8.5	—	10.5	ns
$t_{SPTOE/DIS}$	Input to Output Shared Product Term Output Enable/Disable	—	6.0	—	7.0	—	7.5	—	8.5	—	10.5	ns
$t_{GOE/DIS}$	Global OE Input to Output Enable/Disable	—	4.5	—	5.5	—	5.5	—	6.5	—	7.5	ns
t_{CW}	Clock Width, High or Low	1.5	—	1.5	—	1.5	—	1.8	—	2.5	—	ns
t_{GW}	Gate Width Low (for Low Transparent) or High (for High Transparent)	1.5	—	1.5	—	1.5	—	1.8	—	2.5	—	ns
t_{WIR}	Input Register Clock Width, High or Low	1.5	—	1.5	—	1.5	—	1.8	—	2.5	—	ns
t_{SKEW}	Clock-to-Out Skew, Block Level	—	0.6	—	0.6	—	0.6	—	0.6	—	1.0	ns
f_{MAX} [4]	Clock Frequency with Internal Feedback	—	300	—	275	—	250	—	250	—	150	MHz
f_{MAX} (Ext.)	Clock Frequency with External Feedback, $1/(t_S + t_{CO})$	—	200	—	171	—	166	—	149	—	105	MHz
f_{MAX} (Tog.)	Clock Frequency Max. Toggle	—	333	—	333	—	333	—	277	—	200	MHz
f_{MAX} (CAMC)[5]	Clock Frequency to CAM (Configure Mode)	—	280	—	280	—	230	—	230	—	168	MHz
f_{MAX} (CAM)[5]	Clock Frequency to CAM (Compare Mode)	—	150	—	150	—	150	—	135	—	90	MHz

ispXPLD 5000MX Family Internal Switching Characteristics (Continued)

Over Recommended Operating Conditions

Parameter	Description	Base Parameter	-4		-45		-5		-52		-75		Units
			Min.	Max.	Min.	Max.	Min.	Max.	Min.	Max.	Min.	Max.	
$t_{FIFOWES}$	Write-Enable setup before Write Clock	—	2.33	—	2.33	—	2.91	—	2.91	—	3.03	—	ns
$t_{FIFOWEH}$	Write-Enable hold after Write Clock	—	-2.95	—	-2.95	—	-2.36	—	-2.36	—	-2.27	—	ns
$t_{FIFORES}$	Read-Enable setup before Read Clock	—	2.69	—	2.35	—	2.79	—	2.38	—	4.14	—	ns
$t_{FIFOREH}$	Read-Enable hold after Read Clock	—	-3.17	—	-3.17	—	-2.53	—	-2.53	—	-2.44	—	ns
$t_{FIFORSTO}$	Reset to Output Delay	—	—	3.30	—	3.30	—	4.13	—	4.13	—	4.29	ns
$t_{FIFORSTR}$	Reset Recovery Time	—	1.20	—	1.20	—	1.50	—	1.50	—	1.56	—	ns
$t_{FIFORSTPW}$	Reset Pulse Width	—	0.14	—	0.14	—	0.18	—	0.18	—	0.19	—	ns
$t_{FIFORCLKO}$	Read Clock to FIFO Out Delay	—	—	3.73	—	3.73	—	4.66	—	4.66	—	4.84	ns
CAM – Update Mode													
t_{CAMMSS}	Memory Select Setup before CLK	—	1.40	—	0.70	—	1.50	—	1.40	—	1.44	—	ns
t_{CAMMSH}	Memory Select Hold after CLK	—	-0.01	—	-0.01	—	-0.01	—	-0.01	—	-0.01	—	ns
$t_{CAMENMSKS}$	Enable Mask Register Setup Time before CLK	—	-0.27	—	-0.27	—	-0.22	—	-0.22	—	-0.21	—	ns
$t_{CAMENMSKH}$	Enable Mask Register Setup Time after CLK	—	-0.01	—	-0.01	—	-0.01	—	-0.01	—	-0.01	—	ns
$t_{CAMADDS}$	Address Setup Time before Clock	—	-0.27	—	-0.27	—	-0.22	—	-0.22	—	-0.21	—	ns
$t_{CAMADDH}$	Address Hold Time after Clock	—	-0.01	—	-0.01	—	-0.01	—	-0.01	—	-0.01	—	ns
$t_{CAMDATAS}$	Data Setup Time before Clock	—	-0.41	—	-0.41	—	-0.33	—	-0.33	—	-0.31	—	ns
$t_{CAMDATAH}$	Data Hold Time after Clock	—	-0.01	—	-0.01	—	-0.01	—	-0.01	—	-0.01	—	ns
t_{CAMDCS}	"Don't Care" Setup Time before Clock	—	-0.27	—	-0.27	—	-0.22	—	-0.22	—	-0.21	—	ns
t_{CAMDCH}	"Don't Care" Hold Time after Clock	—	-0.01	—	-0.01	—	-0.01	—	-0.01	—	-0.01	—	ns
t_{CAMRWS}	R/W Setup Time before Clock	—	-0.27	—	-0.27	—	-0.22	—	-0.22	—	-0.21	—	ns
t_{CAMRWH}	R/W Enable Hold Time after Clock	—	-0.01	—	-0.01	—	-0.01	—	-0.01	—	-0.01	—	ns
t_{CAMCES}	Clock Enable Setup Time before Clock	—	1.55	—	1.55	—	1.94	—	1.94	—	2.02	—	ns
t_{CAMCEH}	Clock Enable Hold Time after Clock	—	-2.95	—	-2.95	—	-2.36	—	-2.36	—	-2.27	—	ns

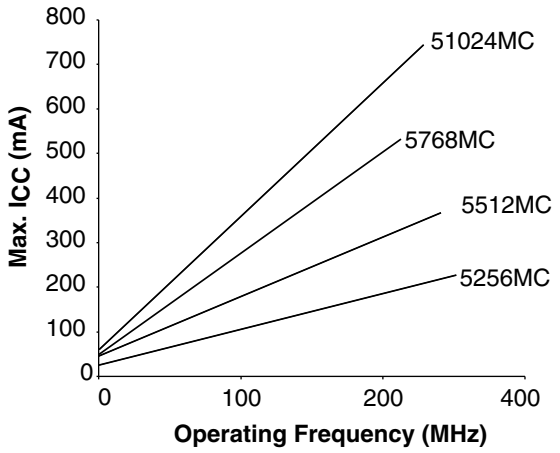
Boundary Scan Timing Specifications

Over Recommended Operating Conditions

Parameter	Description	Min	Max	Units
t_{BTCP}	TCK [BSCAN] clock pulse width	40	—	ns
t_{BTCPH}	TCK [BSCAN] clock pulse width high	20	—	ns
t_{BTCPL}	TCK [BSCAN] clock pulse width low	20	—	ns
t_{BTS}	TCK [BSCAN] setup time	8	—	ns
t_{BTH}	TCK [BSCAN] hold time	10	—	ns
t_{BTRF}	TCK [BSCAN] rise/fall time	50	—	mV/ns
t_{BTCO}	TAP controller falling edge of clock to valid output	—	10	ns
$t_{BTCODIS}$	TAP controller falling edge of clock to valid disable	—	10	ns
t_{BTCOEN}	TAP controller falling edge of clock to valid enable	—	10	ns
t_{BTCRS}	BSCAN test capture register setup time	8	—	ns
t_{BTCRH}	BSCAN test capture register hold time	10	—	ns
t_{BUTCO}	BSCAN test update register, falling edge of clock to valid output	—	25	ns
$t_{BTUODIS}$	BSCAN test update register, falling edge of clock to valid disable	—	25	ns
$t_{BTUPOEN}$	BSCAN test update register, falling edge of clock to valid enable	—	25	ns

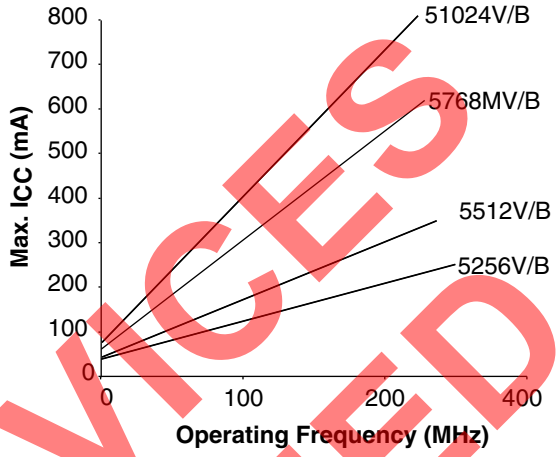
Power Consumption

ispXPLD 5000MC Typical I_{CC} vs. Frequency



Note: The device is configured with maximum number of 16-bit counters, no PLL, typical current at 1.8V, 25°C.

ispXPLD 5000MV/B Typical I_{CC} vs. Frequency



Note: The device is configured with maximum number of 16-bit counters, no PLL, typical current at 3.3V (MV) or 2.5V (MB), 25°C.

Power Estimation Coefficients

Device	K0	K1	K2	K3	K4	K5	K6	K7	DC	
									ispXPLD 5000MC	ispXPLD 5000MV/B
ispXPLD 5256	2.2	8.4	7	12	100	0.1379	0.0433	6.476	16	24
ispXPLD 5512	2.2	8.4	9.4	18	151	0.1379	0.0433	6.476	17	25
ispXPLD 5768	2.2	8.4	10.2	21	170	0.1379	0.0433	6.476	27	36
ispXPLD 51024	2.2	8.4	13	27.6	200	0.1379	0.0433	6.476	35	43

Note: For further information about the use of these coefficients, refer to TN1031 – Power Estimation in ispXPLD 5000MX Devices.

Memory Coefficients

Device	K8	K9	K10	K11
ispXPLD 5256	0.004719	0.0924	4.4	2.9
ispXPLD 5512	0.004719	0.0924	4.4	2.9
ispXPLD 5768	0.004719	0.0924	4.4	2.9
ispXPLD 51024	0.004719	0.0924	4.4	2.9

- K0 = Current per MFB input (µA/MHz)
- K1 = Current per Product Term (µA/MHz)
- K2 = Current per GRP from MFB (µA/MHz)
- K3 = Current per GRP from I/O (µA/MHz)
- K4 = Global clock tree current (µA/MHz)
- K5 = PLL digital (mA/MHz)
- K6 = PLL analog (mA/MHz)
- K7 = PLL analog baseline (mA)
- DC = Baseline current at 0Mhz (mA)
- K8 = CAM frequency component (mA/MHz)
- K9 = CAM DC component (mA)
- K10 = Current per row decoder (µA/MHz)
- K11 = Current per column driver (µA/MHz)

Power Estimation Equations

ICC = ICC_DC + IMFB_CPLD + IMFB_ SRAM/PDPRAM/FIFO + IMFB_DPRAM + IMFB_CAM + IPLL_D

ICC_DC
Use the appropriate value for 5000MC (1.8V power supply) or 5000MV/B (2.5V/3.3V power supply) from the data sheet.

IMFB_CPLD
= ((**K0** * CPLD MFB inputs + **K1** * CPLD Logical Product Terms + **K2** * CPLD GRP from MFB + **K3** * CPLD GRP from IFB) * AF+ **K4**) * FREQ / 1000µA/mA

IMFB_CAM
= CAM Memory MFBs * ((FREQ * **K8**) + **K9**) (CAM operating in typical mode)

IMFB_ SRAM/PDPRAM/FIFO
= (WR_ PERCENT * (**K1** + WR_ PERCENT * 8 * **K0** + **K10** + **K11**) + RD_ PERCENT * (**K1** + 128 * RD_PERCENT * **K0** + 8 * OSW_PERCENT * **K2**)) * SRAM/PDPRAM/FIFO Memory MFBs * FREQ / 1000µA/mA

IMFB_ DPRAM
= (WR_ PERCENT * (2 * **K1** + 2 * WR_ PERCENT * 8 * **K0** + **K10** + **K11**) + RD_ PERCENT * (2 * **K1** + 2 * 128 * RD_PERCENT * **K0** + 8 * OSW_PERCENT * **K2**)) * DPRAM Memory MFBs * FREQ / 1000µA/mA

IPLL_D
= **K5** * PLL_FREQ * number of PLLs used. IPPL_D is the PLL digital component of the VCC supply current.

Analog portion of PLL supply current consumption, from PLL power pin:

IPLL_A = (**K6** * PLL_FREQ + **K7**) * number of PLLs used

Notes:

- ICC = Current consumption of VCC power supply (mA)
- ICC-DC = ICC DC component – Current consumption at 0Mhz (mA)
- IMFB_CPLD = CPLD (non-memory logic) current consumption (mA)
- IMFB_SRAM/PDPRAM/FIFO = Current consumption for SRAM, PDPRAM, and FIFO (mA)
- IMFB_DPRAM = Current consumption for DPRAM (mA)
- IMFB_CAM = Current consumption for CAM (mA)
- IPLL_D = PLL Current consumption of digital VCC power supply (mA)
- IPLL_A = PLL analog power pin current consumption (VCCP pin)

ispXPLD 5000MX Power Supply and NC Connections[1]

ispXPLD 5256MX Logic Signal Connections (Continued)

sysIO Bank	LVDS Pair	Primary Macrocell/ Function	Alternate Outputs		Alternate Input	256 fpBGA Ball Number
			Macrocell 1	Macrocell 2		
1	4N	A16/CSB	A9	B9	A17	L5
1	5P	A18/READ	A10	B10	A19	N1
1	5N	A20/CCLK	A11	B11	A21	M2
-	-	VCC	-	-	-	VCC
-	-	DONE	-	-	-	M4
1	6P	A22	A12	B12	A23	N3
1	6N	A24	A13	B13	A25	P4
1	7P	A26	A14	B14	A27	N5
1	7N	A28	A15	B15	A29	M6
-	-	PROGRAMB	-	-	-	R3
-	-	GND (Bank 1)	-	-	-	GND (Bank 1)
-	-	VCCO1	-	-	-	VCC01
-	-	CFG0	-	-	-	L8
1	8P	B2	A16	B16	B3	T7
1	8N	B4	A17	B17	-	R7
1	9P	B5	A18	B18	-	N7
1	9N	B6	A19	B19	B7	P7
1	10P	B8	A20	B20	B9	T8
1	10N	B10	A21	B21	B11	R8
1	11P	B12	A22	B22	B13	M8
1	11N	B14	A23	B23	B15	P8
1	-	B16/VREF1	-	-	B17	L9
1	12P	B18	A24	B24	B19	N8
1	12N	B20	A25	B25	-	M9
-	-	GND (Bank 1)	-	-	-	GND (Bank 1)
1	13P	B21	A26	B26	-	N10
-	-	VCCO1	-	-	-	VCCO1
1	13N	B22	A27	B27	B23	T9
1	14P	B24	A28	B28	B25	T10
1	14N	B26	A29	B29	B27	R9
-	-	VCC	-	-	-	VCC
1	15P	B28	A30	B30	B29	P9
1	15N	B30	A31	B31	B31	N9
2	16P	C0	C0	D0	C1	T11
2	16N	C2	C1	D1	C3	T12
2	17P	C4	C2	D2	-	P10
2	17N	C5	C3	D3	-	R10
2	18P	C6	C4	D4	C7	R11
-	-	VCCO2	-	-	-	VCCO2
2	18N	C8	C5	D5	C9	M10
-	-	GND (Bank 2)	-	-	-	GND (Bank 2)
2	19P	C10	C6	D6	C11	M11
2	19N	C12	C7	D7	C13	T13

ispXPLD 5768MX Logic Signal Connections (Continued)

sysIO Bank	LVDS Pair	Primary Macrocell/ Function	Alternate Outputs		Alternate Inputs	256 fpBGA Ball Number	484 fpBGA Ball Number
			Macrocell 1	Macrocell 2			
0	126N	S26	S13	-	S27	—	C4
0	126P	S24	S12	-	S25	—	D5

Global Clock LVDS pair options: GCLK0 and GCLK1, as well as GCLK2 and GCLK3, can be paired together to receive differential clocks; where GCLK0 and GCLK3 are the positive LVDS inputs.

ispXPLD 51024MX Logic Signal Connections

sysIO Bank	LVDS Pair	Primary Macrocell/Function	Alternate Outputs		Alternate Input	484 fpBGA Ball Number	672 fpBGA Ball Number
			Macrocell 1	Macrocell 2			
0	159N	AA22	AA11	AB18	AA23	B4	C2
0	159P	AA20	AA10	AB16	AA21	A4	C1
0	160N	AA18	Y17	AA17	AA19	B3	D4
0	160P	AA16	Y16	AA16	AA17	A3	D3
0	161N	AA14	Y15	AA15	AA15	F5	D2
-	-	VCCO0	-	-	-	VCCO0	VCCO0
0	161P	AA12	Y14	AA14	AA13	G6	D1
-	-	GND (Bank 0)	-	-	-	GND (Bank 0)	GND (Bank 0)
0	162N	AA10	Y13	AA13	AA11	H6	E5
0	162P	AA8	Y12	AA12	AA9	G5	E4
0	163N	AA6	AA9	AB14	AA7	D3	E3
0	163P	AA4	AA8	AB12	AA5	D2	E2
0	164N	AA2	AA7	AB10	AA3	E4	E1
-	-	VCC	-	-	-	VCC	VCC
0	164P	AA0	AA6	AB8	AA1	E3	F2
-	-	GND	-	-	-	GND	GND
0	165N	AB30	AA5	AB6	AB31	F4	F5
0	165P	AB28	AA4	AB4	AB29	G4	G6
0	166N	AB26	AA3	AB2	AB27	C2	F4
-	-	VCCO0	-	-	-	VCCO0	VCCO0
0	166P	AB24	AA2	AB0	AB25	C1	F3
-	-	GND (Bank 0)	-	-	-	GND (Bank 0)	GND (Bank 0)
0	167N	AB22	AA1	-	AB23	F3	F1
0	167P	AB20	AA0	-	AB21	G3	G1
0	168N	AB18	AA31	-	AB19	H4	G5
-	-	VCC	-	-		VCC	VCC
0	168P	AB16	AA30	-	AB17	J4	G4
0	169N	AB14	Y11	AA11	AB15	H5	H7
0	169P	AB12/CLK_OUT0	Y10	AA10	AB13	J5	J7
0	170N	AB10	Y9	AA9	AB11	E2	G3
0	170P	AB8	Y8	AA8	AB9	F2	G2
-	-	GND	-	-	-	GND	GND
0	171N	AB6	Y7	AA7	AB7	D1	H6
-	-	VCCO0	-	-	-	VCCO0	VCCO0
0	171P	AB4	Y6	AA6	AB5	E1	J6
-	-	GND (Bank 0)	-	-	-	GND (Bank 0)	GND (Bank 0)
0	172N	AB2	Y5	AA5	AB3	J3	H5
0	172P	AB0/PLL_RST0	Y4	AA4	AB1	H2	H4
0	173N	AC30	AC31	AE31	AC31	G2	H3
0	173P	AC28/PLL_FBK0	AC30	AE30	AC29	G1	H2
0	174N	AC26	AC29	AE29	AC27	J6	H1
0	174P	AC24	AC28	AE28	AC25	K4	J1

ispXPLD 51024MX Logic Signal Connections (Continued)

sysIO Bank	LVDS Pair	Primary Macrocell/Function	Alternate Outputs		Alternate Input	484 fpBGA Ball Number	672 fpBGA Ball Number
			Macrocell 1	Macrocell 2			
-	-	TCK	-	-	-	T1	P3
-	-	TDO	-	-	-	V1	P2
1	0P	A30	A0	C0	A31	—	P1
1	0N	A28	A1	C1	A29	—	R1
1	1P	A26	A2	C2	A27	—	P6
1	1N	A24	A3	C3	A25	—	R6
1	2P	A22	A4	C4	A23	—	P7
1	2N	A20	A5	C5	A21	—	R7
-	-	GND (Bank 1)	-	-	-	GND (Bank 1)	GND (Bank 1)
1	3P	A18	A6	C6	A19	—	R4
-	-	VCCO1	-	-	-	VCCO1	VCCO1
1	3N	A16	A7	C7	A17	—	R5
-	-	GND	-	-	-	GND	GND
1	4P	A14	A8	C8	A15	—	R3
-	-	VCC	-	-	-	VCC	VCC
1	4N	A12	A9	C9	A13	—	R2
1	5P	A10	A10	C10	A11	—	T2
1	5N	A8	A11	C11	A9	—	T3
1	6P	A6	A12	C12	A7	—	T4
1	6N	A4	A13	C13	A5	—	T5
1	7P	A2	A14	C14	A3	—	U2
1	7N	A0	A15	C15	A1	—	U3
-	-	GND (Bank 1)	-	-	-	GND (Bank 1)	GND (Bank 1)
1	8P	C30	A16	C16	C31	—	U4
-	-	VCCO1	-	-	-	VCCO1	VCCO1
1	8N	C28	A17	C17	C29	—	U5
1	9P	C26	A18	C18	C27	—	T6
1	9N	C24	A19	C19	C25	—	U6
1	10P	C22	A20	C20	C23	—	T7
1	10N	C20	A21	C21	C21	—	U7
1	11P	C18	A22	C22	C19	—	U1
1	11N	C16	A23	C23	C17	—	V1
1	12P	C14	A24	C24	C15	—	V2
1	12N	C12	A25	C25	C13	—	V3
-	-	GND (Bank 1)	-	-	-	GND (Bank 1)	GND (Bank 1)
1	13P	C10	A26	C26	C11	—	V5
-	-	VCCO1	-	-	-	VCCO1	VCCO1
1	13N	C8	A27	C27	C9	—	V4
-	-	GND	-	-	-	GND	GND
1	14P	C6	A28	C28	C7	—	W2
-	-	VCC	-	-	-	VCC	VCC
1	14N	C4	A29	C29	C5	—	W3
1	15P	C2	A30	C30	C3	—	W4

ispXPLD 51024MX Logic Signal Connections (Continued)

sysIO Bank	LVDS Pair	Primary Macrocell/Function	Alternate Outputs		Alternate Input	484 fpBGA Ball Number	672 fpBGA Ball Number
			Macrocell 1	Macrocell 2			
-	-	VCCO2	-	-	-	VCCO2	VCCO2
2	79N	N10	P5	N5	N11	—	V26
-	-	GND (Bank 2)	-	-	-	GND (Bank 2)	GND (Bank 2)
2	80P	N12	P6	N6	N13	—	V22
2	80N	N14	P7	N7	N15	—	V23
2	81P	N16	P8	N8	N17	—	V24
2	81N	N18	P9	N9	N19	—	V25
2	82P	N20	P10	N10	N21	—	U20
2	82N	N22	P11	N11	N23	—	T20
2	83P	N24	P12	N12	N25	—	U26
2	83N	N26	P13	N13	N27	—	U25
2	84P	N28	P14	N14	N29	—	U21
-	-	VCCO2	-	-	-	VCCO2	VCCO2
2	84N	N30	P15	N15	N31	—	T21
-	-	GND (Bank 2)	-	-	-	GND (Bank 2)	GND (Bank 2)
2	85P	P0	P16	N16	P1	—	U22
2	85N	P2	P17	N17	P3	—	U23
2	86P	P4	P18	N18	P5	—	U24
2	86N	P6	P19	N19	P7	—	T24
2	87P	P8	P20	N20	P9	—	T23
2	87N	P10	P21	N21	P11	—	T22
2	88P	P12	P22	N22	P13	—	T25
-	-	VCC	-	-	-	VCC	VCC
2	88N	P14	P23	N23	P15	—	R26
-	-	GND	-	-	-	GND	GND
2	89P	P16	P24	N24	P17	—	R25
-	-	VCCO2	-	-	-	VCCO2	VCCO2
2	89N	P18	P25	N25	P19	—	R24
-	-	GND (Bank 2)	-	-	-	GND (Bank 2)	GND (Bank 2)
2	90P	P20	P26	N26	P21	—	R21
2	90N	P22	P27	N27	P23	—	P21
2	91P	P24	P28	N28	P25	—	R22
2	91N	P26	P29	N29	P27	—	R23
2	92P	P28	P30	N30	P29	—	R20
2	92N	P30	P31	N31	P31	—	P20
-	-	TOE	-	-	-	W22	P25
-	-	RESET	-	-	-	V22	P24
-	-	GOE0	-	-	-	T22	P23
-	-	GOE1	-	-	-	R22	P22
-	-	GNDP	-	-	-	See Power Supply and NC Connections Table	
-	GCLK3N	GCLK2	-	-	-	P16	N26
-	-	VCCP	-	-	-	See Power Supply and NC Connections Table	

ispXPLD 5000MB (2.5V) Lead-Free Commercial Devices

Device	Part Number	Macrocells	Voltage (V)	t_{PD} (ns)	Package	Pin/Ball Count	I/O	Grade
LC5256MB	LC5256MB-4FN256C	256	2.5	4.0	Lead-free fpBGA	256	141	C
	LC5256MB-5FN256C	256	2.5	5.0	Lead-free fpBGA	256	141	C
	LC5256MB-75FN256C	256	2.5	7.5	Lead-free fpBGA	256	141	C
LC5512MB	LC5512MB-45QN208C	512	2.5	4.5	Lead-free PQFP	208	149	C
	LC5512MB-75QN208C	512	2.5	7.5	Lead-free PQFP	208	149	C
	LC5512MB-45FN256C	512	2.5	4.5	Lead-free fpBGA	256	193	C
	LC5512MB-75FN256C	512	2.5	7.5	Lead-free fpBGA	256	193	C
	LC5512MB-45FN484C	512	2.5	4.5	Lead-free fpBGA	484	253	C
	LC5512MB-75FN484C	512	2.5	7.5	Lead-free fpBGA	484	253	C
LC5768MB	LC5768MB-5FN256C	768	2.5	5.0	Lead-free fpBGA	256	193	C
	LC5768MB-75FN256C	768	2.5	7.5	Lead-free fpBGA	256	193	C
	LC5768MB-5FN484C	768	2.5	5.0	Lead-free fpBGA	484	317	C
	LC5768MB-75FN484C	768	2.5	7.5	Lead-free fpBGA	484	317	C
LC51024MB	LC51024MB-52FN484C	1024	2.5	5.2	Lead-free fpBGA	484	317	C
	LC51024MB-75FN484C	1024	2.5	7.5	Lead-free fpBGA	484	317	C
	LC51024MB-52FN672C	1024	2.5	5.2	Lead-free fpBGA	672	381	C
	LC51024MB-75FN672C	1024	2.5	7.5	Lead-free fpBGA	672	381	C

ispXPLD 5000MB (2.5V) Lead-Free Industrial Devices

Device	Part Number	Macrocells	Voltage (V)	t_{PD} (ns)	Package	Pin/Ball Count	I/O	Grade
LC5256MB	LC5256MB-5FN256I	256	2.5	5.0	Lead-free fpBGA	256	141	I
	LC5256MB-75FN256I	256	2.5	7.5	Lead-free fpBGA	256	141	I
LC5512MB	LC5512MB-75QN208I	512	2.5	7.5	Lead-free PQFP	208	149	I
	LC5512MB-75FN256I	512	2.5	7.5	Lead-free fpBGA	256	193	I
	LC5512MB-75FN484I	512	2.5	7.5	Lead-free fpBGA	484	253	I
LC5768MB	LC5768MB-75FN256I	768	2.5	7.5	Lead-free fpBGA	256	193	I
	LC5768MB-75FN484I	768	2.5	7.5	Lead-free fpBGA	484	317	I
LC51024MB	LC51024MB-75FN484I	1024	2.5	7.5	Lead-free fpBGA	484	317	I
	LC51024MB-75FN672I	1024	2.5	7.5	Lead-free fpBGA	672	381	I

ispXPLD 5000MV (3.3V) Lead-Free Commercial Devices

Device	Part Number	Macrocells	Voltage (V)	t_{PD} (ns)	Package	Pin/Ball Count	I/O	Grade
LC5256MV	LC5256MV-4FN256C	256	3.3	4.0	Lead-free fpBGA	256	141	C
	LC5256MV-5FN256C	256	3.3	5.0	Lead-free fpBGA	256	141	C
	LC5256MV-75FN256C	256	3.3	7.5	Lead-free fpBGA	256	141	C

ispXPLD 5000MV (3.3V) Lead-Free Commercial Devices (Continued)

Device	Part Number	Macrocells	Voltage (V)	t_{PD} (ns)	Package	Pin/Ball Count	I/O	Grade
LC5512MV	LC5512MV-45QN208C	512	3.3	4.5	Lead-free PQFP	208	149	C
	LC5512MV-75QN208C	512	3.3	7.5	Lead-free PQFP	208	149	C
	LC5512MV-45FN256C	512	3.3	4.5	Lead-free fpBGA	256	193	C
	LC5512MV-75FN256C	512	3.3	7.5	Lead-free fpBGA	256	193	C
	LC5512MV-45FN484C	512	3.3	4.5	Lead-free fpBGA	484	253	C
	LC5512MV-75FN484C	512	3.3	7.5	Lead-free fpBGA	484	253	C
LC5768MV	LC5768MV-5FN256C	768	3.3	5.0	Lead-free fpBGA	256	193	C
	LC5768MV-75FN256C	768	3.3	7.5	Lead-free fpBGA	256	193	C
	LC5768MV-5FN484C	768	3.3	5.0	Lead-free fpBGA	484	317	C
	LC5768MV-75FN484C	768	3.3	7.5	Lead-free fpBGA	484	317	C
LC51024MV	LC51024MV-52FN484C	1024	3.3	5.2	Lead-free fpBGA	484	317	C
	LC51024MV-75FN484C	1024	3.3	7.5	Lead-free fpBGA	484	317	C
	LC51024MV-52FN672C	1024	3.3	5.2	Lead-free fpBGA	672	381	C
	LC51024MV-75FN672C	1024	3.3	7.5	Lead-free fpBGA	672	381	C

ispXPLD 5000MV (3.3V) Lead-Free Industrial Devices

Device	Part Number	Macrocells	Voltage (V)	t_{PD} (ns)	Package	Pin/Ball Count	I/O	Grade
LC5256MV	LC5256MV-5FN256I	256	3.3	5.0	Lead-free fpBGA	256	141	I
	LC5256MV-75FN256I	256	3.3	7.5	Lead-free fpBGA	256	141	I
LC5512MV	LC5512MV-75QN208I	512	3.3	7.5	Lead-free PQFP	208	149	I
	LC5512MV-75FN256I	512	3.3	7.5	Lead-free fpBGA	256	193	I
	LC5512MV-75FN484I	512	3.3	7.5	Lead-free fpBGA	484	253	I
LC5768MV	LC5768MV-75FN256I	768	3.3	7.5	Lead-free fpBGA	256	193	I
	LC5768MV-75FN484I	768	3.3	7.5	Lead-free fpBGA	484	317	I
LC51024MV	LC51024MV-75FN484I	1024	3.3	7.5	Lead-free fpBGA	484	317	I
	LC51024MV-75FN672I	1024	3.3	7.5	Lead-free fpBGA	672	381	I

For Further Information

In addition to this data sheet, the following technical notes may be helpful when designing with the ispXPLD 5000MX family:

- TN1000 – sysIO Usage Guidelines for Lattice Devices
- TN1003 – sysCLOCK PLL Usage Guide for ispXPGA, ispGDX2, ispXPLD and ispMACH 5000VG Devices
- TN1031 – Power Estimation in ispXPLD 5000MX Devices
- TN1030 – Using Memory in ispXPLD 5000MX Devices
- TN1026 – ispXP Configuration Usage Guidelines